

2N6426G

2N6426G Information

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Part Number	2N6426G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN DARL 40V 0.5A TO92
Package	TO-226-3, TO-92-3 (TO-226AA)
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

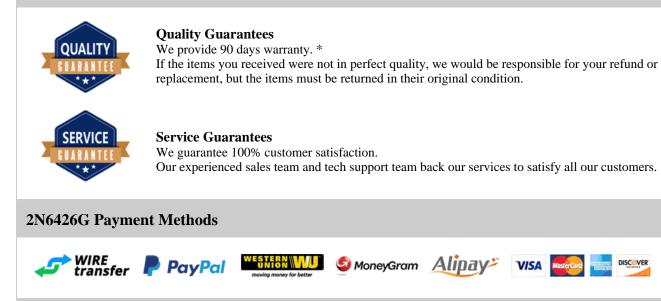
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2N6426G Specifications

Manufacturer Part Number	2N6426G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-226-3, TO-92-3 (TO-226AA)
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	500mA
Voltage - Collector Emitter Breakdown (Max)	40V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 500µA, 500mA
Current - Collector Cutoff (Max)	1μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	30000 @ 100mA, 5V
Power - Max	625mW
Frequency - Transition	-
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 (TO-226AA)
Supplier Device Package	TO-92-3
	Report errors?

2N6426G Guarantees



2N6426G Shipping Methods



DISCOVER

If you have any question about 2N6426G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com